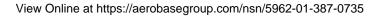
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Memory Microcircuit - Page 1 of 1



Storage Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Burn in, mil-std-883, class b

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Voltage Rating And Type Per Characteristic:

5.0 volts total supply

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Terminal Type And Quantity:

28 leadless

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

